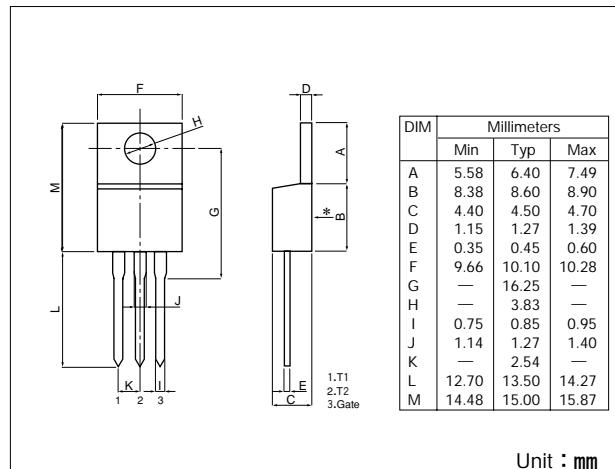
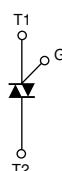


TRIAC (NON-ISOLATED TYPE)

TMG16C60

TMG16C60 are non-isolated triac suitable for wide range of applications like copier, microwave oven, solid state switch, motor control, light and heater control.

- $I_{T(RMS)}$ 16A
- High surge capability 170A
- Non-isolated type



■ Maximum Ratings

($T_j=25^\circ\text{C}$ unless otherwise specified)

Symbol	Item	Ratings	Unit
		TMG16C60	
V_{DRM}	Repetitive Peak Off-State Voltage	600	V

Symbol	Item	Conditions	Ratings	Unit
$I_{T(RMS)}$	R.M.S. On-State Current	$T_c=98^\circ\text{C}$	16	A
I_{TSM}	Surge On-State Current	One cycle, 50Hz/60Hz, peak, non-repetitive	155/170	A
I^2t	I^2t	Value for one cycle of surge current	120	A^2s
P_{GM}	Peak Gate Power Dissipation		5	W
$P_{G(AV)}$	Average Gate Power Dissipation		0.5	W
I_{GM}	Peak Gate Current		2	A
V_{GM}	Peak Gate Voltage		10	V
T_j	Operating Junction Temperature		-40 to +125	$^\circ\text{C}$
T_{stg}	Storage Temperature		-40 to +125	$^\circ\text{C}$
	Mass		2	g

■ Electrical Characteristics

Symbol	Item	Conditions	Ratings			Unit
			Min.	Typ.	Max.	
I_{DRM}	Repetitive Peak Off-State Current	$V_D=V_{DRM}$, Single phase, half wave, $T_j=125^\circ\text{C}$			2	mA
V_{TM}	Peak On-State Voltage	$I_t=20\text{A}$, Inst. measurement			1.4	V
I_{GT1}^+ 1	Gate Trigger Current	$V_D=6\text{V}$, $R_L=10\Omega$			30	mA
I_{GT1}^- 2					30	
I_{GT3}^+ 3					—	
I_{GT3}^- 4					30	
V_{GT1}^+ 1	Gate Trigger Voltage	$V_D=6\text{V}$, $R_L=10\Omega$			1.5	V
V_{GT1}^- 2					1.5	
V_{GT3}^+ 3					—	
V_{GT3}^- 4					1.5	
V_{GD}	Non-Trigger Gate Voltage	$T_j=125^\circ\text{C}$, $V_D=\frac{1}{2}V_{DRM}$	0.2			V
$(dv/dt)_c$	Critical Rate of Rise off-State Voltage at commutation	$T_j=125^\circ\text{C}$, $(dv/dt)_c=-8\text{A/ms}$, $V_D=\frac{2}{3}V_{DRM}$	10			$\text{V}/\mu\text{s}$
I_H	Holding Current			25		mA
$R_{th(j-c)}$	Thermal Impedance	Junction to case			1.4	$^\circ\text{C}/\text{W}$

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